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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/707,358	12/08/2003	Yu-Piao Wang	11417-US-PA	1357	
31561	7590 11/30/2004		EXAMINER		
JIANQ CHYUN INTELLECTUAL PROPERTY OFFICE 7 FLOOR-1, NO. 100 ROOSEVELT ROAD, SECTION 2 TAIPEI, 100			HU, SHOUXIANG		
			ART UNIT	RT UNIT PAPER NUMBER	
			2811		
TAIWAN			DATE MAILED: 11/30/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.		Applicant(s)				
Office Action Summany	10/707,358		WANG, YU-PIAO				
Office Action Summary	Examiner		Art Unit	ne/			
The MAILING DATE of the	Shouxiang Hu		2811	***************************************			
The MAILING DATE of this communication app Period for Reply	sears on the cover	sheet with the co	rrespondence add	iress			
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repl If NO period for reply is specified above, the maximum statutory period of Failure to reply within the set or extended period for reply within the set or extended	136(a). In no event, howe ly within the statutory mini will apply and will expire \$ e, cause the application to	ver, may a reply be time mum of thirty (30) days SIX (6) MONTHS from the become ABANDONED	ly filed will be considered timely. the mailing date of this con (35 U.S.C. § 133).				
Status							
1)⊠ Responsive to communication(s) filed on 13 S	September 2004.		,				
3) Since this application is in condition for allowa							
closed in accordance with the practice under E	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
5) ☐ Claim(s) is/are allowed. 6) ☑ Claim(s) 20,21,25 and 26 is/are rejected. 7) ☐ Claim(s) is/are objected to.	4a) Of the above claim(s) <u>22-24 and 27</u> is/are withdrawn from consideration. ☐ Claim(s) is/are allowed. ☐ Claim(s) <u>20,21,25 and 26</u> is/are rejected.						
Application Papers							
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) acc Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex	cepted or b) objuiction of the distribution of the distribution is required if the	in abeyance. See e drawing(s) is obje	37 CFR 1.85(a). cted to. See 37 CF	• •			
Priority under 35 U.S.C. § 119		•					
12) ☒ Acknowledgment is made of a claim for foreign a) ☒ All b) ☐ Some * c) ☐ None of: 1. ☒ Certified copies of the priority document 2. ☐ Certified copies of the priority document 3. ☐ Copies of the certified copies of the priority application from the International Burea * See the attached detailed Office action for a list	ts have been rece ts have been rece prity documents ha u (PCT Rule 17.2)	ived. ived in Applicatio ve been received (a)).	n No I in this National S	Stage			
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 20040723.	5) 🔲	Interview Summary (l Paper No(s)/Mail Dat Notice of Informal Pa Other:		-152)			

Art Unit: 2811

DETAILED ACTION

Election/Restrictions

1. Claims 22-24 and 27 are withdrawn from further consideration pursuant to 37 CFR 1.142(b), as being drawn to a nonelected invention, there being no allowable generic or linking claim. Applicant timely traversed the restriction (election) requirement in the reply filed on September 13, 2004.

Applicant's election with traverse of claims 20, 21, 25 and 26 in the above reply is acknowledged. The traversal is on the ground(s) that what shown in Figs. 2A-2D and in Fig. 9 are from a same embodiment of the invention; and that claim 20 is generic to all other species. This is not found persuasive because what shown in Fig. 9 was not identified as one of the listed species in the restriction requirement set forth in the previous office action; and that structure/method of species of at least Figs. 1D, 2D, 3D, 4C, 5D, 6, 7D and 8 are apparently mutually distinctive, regardless whether claim 20 is generic to all of them. Nevertheless, it is noted that, upon the allowance of claim 20, applicant will be entitled to consideration of claims to additional species which are written in dependent form or otherwise include all the limitations of an allowed generic claim as provided by 37 CFR 1.141.

The requirement is still deemed proper and is therefore made FINAL.

Art Unit: 2811

Specification

2. The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

The following title is suggested: --Semiconductor Device having a Lower Parasitic Capacitance--.

Claim Objections

3. Claims 20, 21, 25 and 26 are objected to because of the following informalities and/or defects:

In claim 20, it should be clarified that the first and second gate structures comprise respectively first and second pluralities of portions of the recited gate conductive layer, instead of each comprising the entire gate conductive layer.

Claim 20 recite the term of "between the first gate structures", but fails to clarify the recited "contact" is between two of the recited "first gate structure".

Regarding claim 20, it is further noted that the first gate structures as shown in Fig. 2D are not fully covered by the recited dielectric layer (118).

Regarding claim 21, it is noted that the cap layer (see 136a in Fig. 2D) is not fully and/or exactly located between the contact (120) and the gate conductive layer (134 and 132).

Appropriate correction is required.

Application/Control Number: 10/707,358 Page 4

Art Unit: 2811

Claim Rejections - 35 USC § 102

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 5. Claims 20, 21 and 25, as being supported by the elected species and as being best understood in view of the claim objections above, are rejected under 35 U.S.C. 102(e) as being anticipated by Fujiwara (US 2003/0052353).

Fujiwara discloses a semiconductor device structure (Figs. 1-3; also see Paragraphs 0049, 0052 and 0056), comprising: a gate dielectric layer (8), a plurality of first gate structures (9n(WL), the two middle ones in the MCFA section) and a plurality of second gate structures (9n(WL), the two side ones in the MCFA section), each having a gate conductive layer 9n) with a cap and spacers (10 and 13, respectively; both silicon nitride); a self-aligned contact (20) disposed in a dielectric layer (16; SiO2, which naturally has a lower dielectric constant that the silicon nitride spacers and cap therein); and, a conductive line (BL).

Claim Rejections - 35 USC § 103

6. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

Application/Control Number: 10/707,358 Page 5

Art Unit: 2811

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

7. Claim 26, as being supported by the elected species and as being best understood in view of the claim objections above, is rejected under 35 U.S.C. 103(a) as being unpatentable over Fujiwara in view of claim Ligon (US 6,630,721).

The disclosure of Fujiwara is discussed as applied to claims 20, 21 and 25 above.

Although Fujiwara does not expressly disclose that a metal silicide can be formed on a sidewall of the gate conductive layer of the second gate structures, one of ordinary skill in the art would readily recognize that such a metal silicide can be desirably formed for reducing the gate resistance, as evidenced in Ligon (see the vertical portion of 54 in the cover page figure).

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to incorporate the side silicide of Ligon into the gate structures of Fujiwara, so that a semiconductor device with reduced gate resistance would b obtained.

Conclusion

8. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. References C-G are cited as being related to a gate structure.

Application/Control Number: 10/707,358

Art Unit: 2811

Any inquiry concerning this communication or earlier communications from the

Page 6

examiner should be directed to Shouxiang Hu whose telephone number is 571-272-

1654. The examiner can normally be reached on Monday through Thursday, 7:30 AM

to 6:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Eddie C. Lee can be reached on 571-272-1732. The fax phone number for

the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the

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Business Center (EBC) at 866-217-9197 (toll-free).

SH

November 22, 2004 Shoustiegettee

SHOUXIANG HU PRIMARY EXAMINER